

54ABT373

Octal Transparent Latch with TRI-STATE® Outputs

General Description

The 'ABT373 consists of eight latches with TRI-STATE outputs for bus organized system applications. The flip-flops appear transparent to the data when Latch Enable (LE) is HIGH. When LE is LOW, the data that meets the setup times is latched. Data appears on the bus when the Output Enable (\overline{OE}) is LOW. When \overline{OE} is HIGH the bus output is in the high impedance state.

Features

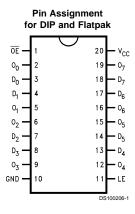
- TRI-STATE outputs for bus interfacing
- Output sink capability of 48 mA, source capability of

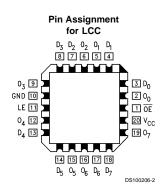
- Guaranteed multiple output switching specifications
- Output switching specified for both 50 pF and 250 pF loads
- Guaranteed simultaneous switching, noise level and dynamic threshold performance
- Guaranteed latchup protection
- High impedance glitch free bus loading during entire power up and power down
- Nondestructive hot insertion capability
- Standard Microcircuit Drawing (SMD) 5962-9321801

Ordering Code

Military	Package Number	Package Description	
54ABT373J-QML	J20A	20-Lead Ceramic Dual-In-Line	
54ABT373W-QML	W20A	20-Lead Cerpack	
54ABT373E-QML	E20A	20-Lead Ceramic Leadless Chip Carrier, Type C	

Connection Diagrams





Pin Names	Description
D ₀ -D ₇	Data Inputs
LE	Latch Enable Input
	(Active HIGH)
ŌĒ	Output Enable Input
	(Active LOW)
O ₀ -O ₇	TRI-STATE Latch
	Outputs

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Functional Description

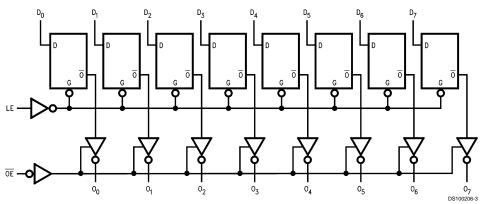
The 'ABT373 contains eight D-type latches with TRI-STATE output buffers. When the Latch Enable (LE) input is HIGH, data on the D_n inputs enters the latches. In this condition the latches are transparent, i.e., a latch output will change state each time its D input changes. When LE is LOW, the latches store the information that was present on the D inputs a setup time preceding the HIGH-to-LOW transition of LE. The TRI-STATE buffers are controlled by the Output Enable (\overline{OE}) input. When $\overline{\text{OE}}$ is LOW, the buffers are in the bi-state mode. When $\overline{\text{OE}}$ is HIGH the buffers are in the high impedance mode but this does not interfere with entering new data into the latches.

Truth Table

	Inputs		Output
LE	ŌĒ	D _n	O _n
Н	L	Η	Н
Н	L	L	L
L	L	Х	O _n (no change)
Х	Н	Х	Z

- H = HIGH Voltage Level L = LOW Voltage Level X = Immaterial
- Z = High Impedance State

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Storage Temperature -65°C to +150°C

-55°C to +125°C Ambient Temperature under Bias

Junction Temperature under Bias

-55°C to +175°C Ceramic

V_{CC} Pin Potential to Ground Pin -0.5V to +7.0VInput Voltage (Note 2) -0.5V to +7.0V Input Current (Note 2) -30 mA to +5.0 mA

Voltage Applied to Any Output

in the Disabled or

Power-Off State -0.5V to +5.5V –0.5V to $V_{\mbox{\scriptsize CC}}$ in the HIGH State

Current Applied to Output in LOW State (Max)

twice the rated I_{OL} (mA)

Over Voltage Latchup (I/O)

10V

Recommended Operating Conditions

Free Air Ambient Temperature

-55°C to +125°C Military

Supply Voltage Military

+4.5V to +5.5V

Minimum Input Edge Rate $(\Delta V/\Delta t)$ Data Input 50 mV/ns Enable Input 20 mV/ns

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Symbol Parameter			ABT373		Units	V _{cc}	Conditions
			Min	Тур	Max	1		
V _{IH}	Input HIGH Voltage		2.0			V		Recognized HIGH Signal
V _{IL}	Input LOW Voltage				0.8	V		Recognized LOW Signal
V _{CD}	Input Clamp Diode Voltag	e			-1.2	V	Min	I _{IN} = -18 mA
V _{OH}	Output HIGH Voltage	54ABT	2.5					I _{OH} = -3 mA
	54ABT		2.0			V	Min	I _{OH} = -24 mA
V _{OL}	Output LOW Voltage	54ABT			0.55	V	Min	I _{OL} = 48 mA
I _{IH}	Input HIGH Current				5	μA	Max	V _{IN} = 2.7V (Note 4)
					5			V _{IN} = V _{CC}
I _{BVI}	Input HIGH Current Break	down Test			7	μA	Max	V _{IN} = 7.0V
I _{IL}	Input LOW Current				-5	μΑ	Max	V _{IN} = 0.5V (Note 4)
					-5			V _{IN} = 0.0V
V _{ID}	Input Leakage Test		4.75			V	0.0	I _{ID} = 1.9 μA
								All Other Pins Grounded
I _{OZH}	Output Leakage Current				50	μΑ	0 - 5.5V	V _{OUT} = 2.7V; OE = 2.0V
I _{OZL}	Output Leakage Current				-50	μA	0 - 5.5V	V _{OUT} = 0.5V; OE = 2.0V
Ios	Output Short-Circuit Current		-100		-275	mA	Max	V _{OUT} = 0.0V
I _{CEX}	Output High Leakage Cur	rent			50	μA	Max	V _{OUT} = V _{CC}
I _{ZZ}	Bus Drainage Test				100	μA	0.0	V _{OUT} = 5.5V; All Others GND
I _{CCH}	Power Supply Current				50	μA	Max	All Outputs HIGH
I _{CCL}	Power Supply Current				30	mA	Max	All Outputs LOW
I _{CCZ}	Power Supply Current				50	μΑ	Max	OE = V _{CC}
								All Others at V _{CC} or GND
I _{CCT}	Additional I _{CC} /Input	Outputs Enabled			2.5	mA		V _I = V _{CC} - 2.1V
		Outputs TRI-STATE			2.5	mA	Max	Enable Input V _I = V _{CC} - 2.1V
		Outputs TRI-STATE			2.5	mA		Data Input V _I = V _{CC} - 2.1V
								All Others at V _{CC} or GND
I _{CCD}	Dynamic I _{CC} No Load					mA/	Max	Outputs Open, LE = V _{CC}
	(Note 4)				0.12	MHz		OE = GND, (Note 3)
								One Bit Toggling, 50% Duty Cycle

Note 3: For 8 bits toggling, I_{CCD} < 0.8 mA/MHz.

Note 4: Guaranteed, but not tested.

Symbol	Parameter	54/	ABT	Units
		$T_A = -55^{\circ}$	C to +125°C	
		V _{CC} = 4.5V to 5.5V C _L = 50 pF		
		Min	Max	
t _{PLH}	Propagation Delay	1.0	6.8	ns
t _{PHL}	D _n to O _n	1.0	7.0	
t _{PLH}	Propagation Delay	1.0	7.7	ns
t _{PHL}	LE to O _n	1.5	7.7	
t _{PZH}	Output Enable Time	1.0	6.7	ns
t _{PZL}		1.5	7.2	
t _{PHZ}	Output Disable Time	1.7	8.0	ns
t _{PLZ}		1.0	7.0	

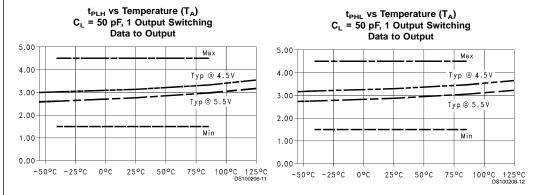
AC Operating Requirements

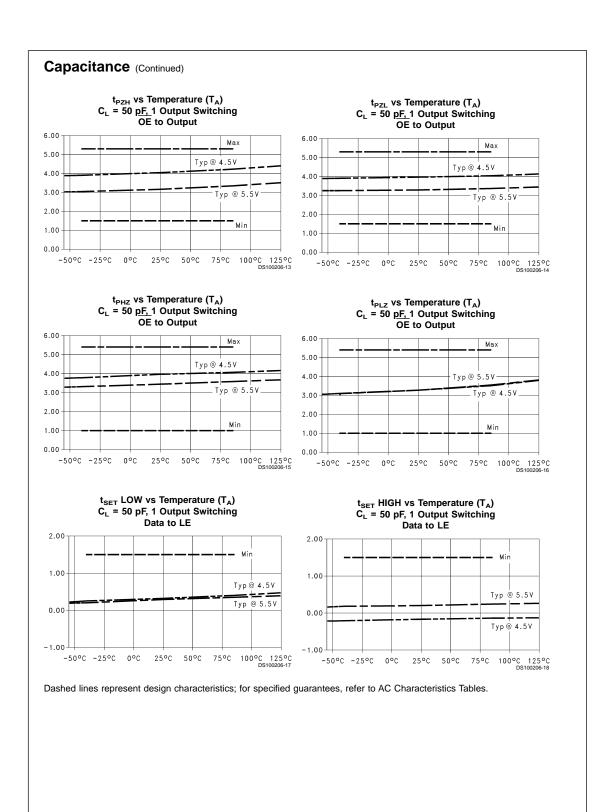
Symbol Parameter		54/ T _A = -55°C	Units	
		V _{CC} = 4.5V to 5.5V C _L = 50 pF		
		Min	Max	
t _s (H)	Setup Time, HIGH	2.5		ns
t _s (L)	or LOW D _n to LE	2.5		
t _h (H)	Hold Time, HIGH	2.5		ns
$t_h(L)$	or LOW D _n to LE	2.5		
t _w (H)	Pulse Width,	3.3		ns
	LE HIGH			

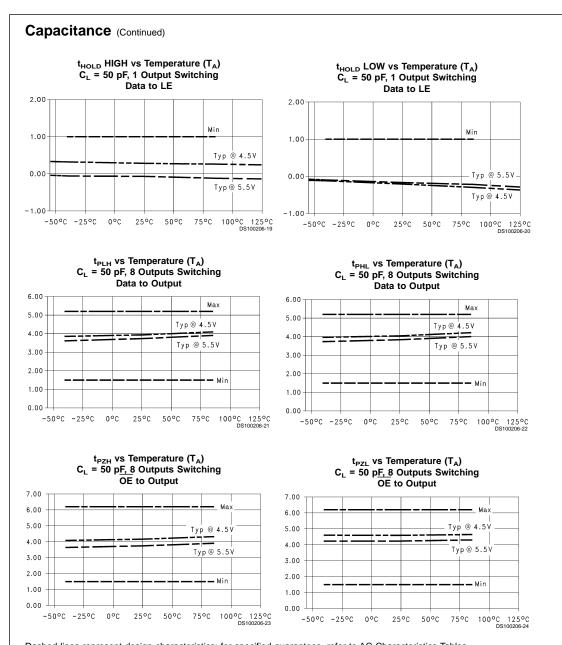
Capacitance

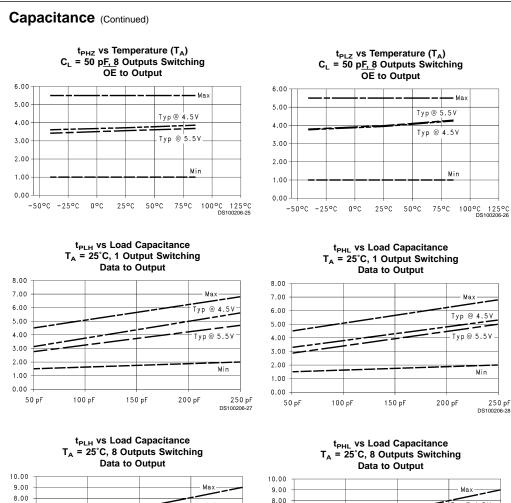
Symbol	Parameter	Тур	Units	Conditions
				(T _A = 25°C)
C _{IN}	Input Capacitance	5	pF	V _{CC} = 0V
C _{OUT} (Note 5)	Output Capacitance	9	pF	V _{CC} = 5.0V

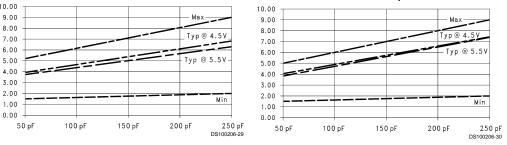
Note 5: C_{OUT} is measured at frequency f = 1 MHz, per MIL-STD-883B, Method 3012.





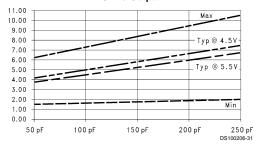




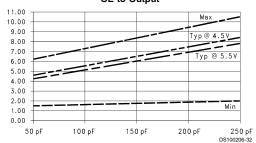


Capacitance (Continued)

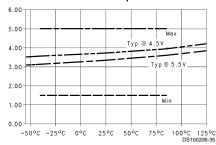
 t_{PZH} vs Load Capacitance $T_A = 25^{\circ}C_{,8}$ Outputs Switching OE to Output



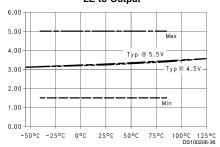
 t_{PZL} vs Load Capacitance $T_A = 25^{\circ}C_{,8}$ Outputs Switching OE to Output



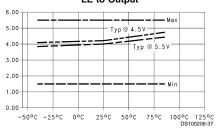
t_{PLH} vs Temperature (T_A)
C_L = 50 pF, 1 Output Switching
LE to Output



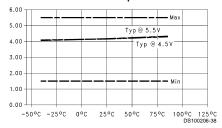
 t_{PHL} vs Temperature (T_A) C_L = 50 pF, 1 Output Switching LE to Output



t_{PLH} vs Temperature (T_A)
C_L = 50 pF, 8 Outputs Switching
LE to Output

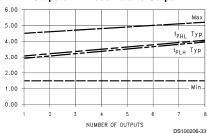


 $t_{\rm PHL}$ vs Temperature (T_A) C_L = 50 pF, 8 Outputs Switching LE to Output

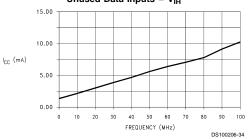


Capacitance (Continued)

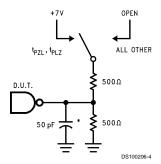
 $t_{\rm PLH}$ and $t_{\rm PHL}$ vs Number Outputs Switching C_L = 50 pF, T_A = 25°C, V_{CC} = 5.0V, Outputs In Phase Data to Output



Typical I_{CC} vs Output Switching Frequency C_L = 0 pF, V_{CC} = V_{IH} = 5.5V, LE = GND, 1 Output Switching at 50% Duty Cycle Data to Output, Transparent Mode with Unused Data Inputs = V_{IH}



AC Loading



*Includes jig and probe capacitance

FIGURE 1. Standard AC Test Load

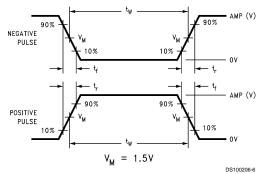


FIGURE 2. Test Input Signal Levels

Amplitude	Rep. Rate	t _w	t _r	t _f
3.0V	1 MHz	500 ns	2.5 ns	2.5 ns

FIGURE 3. Test Input Signal Requirements

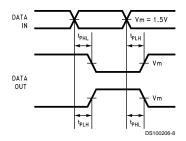


FIGURE 4. Propagation Delay Waveforms for Inverting and Non-Inverting Functions

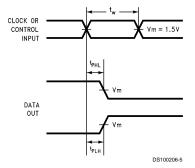


FIGURE 5. Propagation Delay, Pulse Width Waveforms

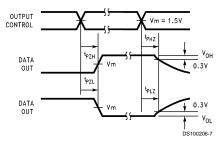


FIGURE 6. TRI-STATE Output HIGH and LOW Enable and Disable Times

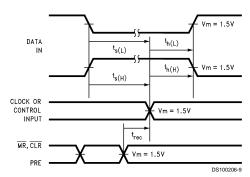
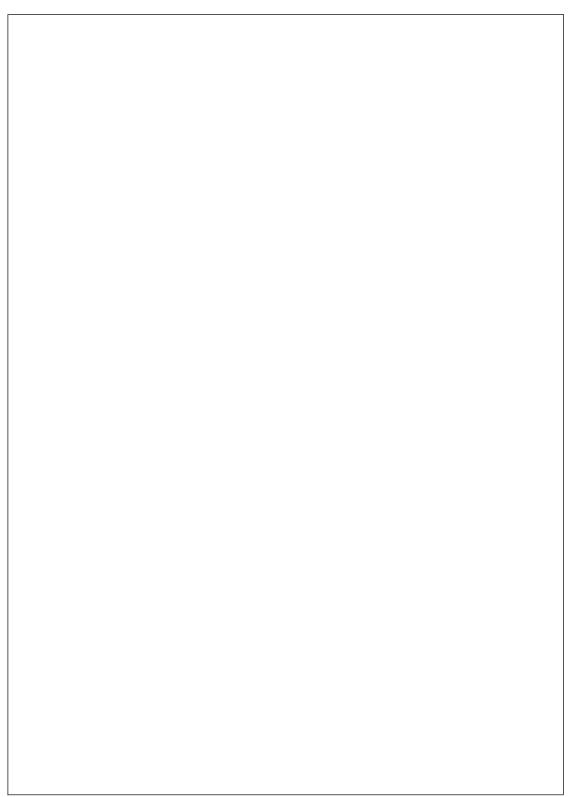
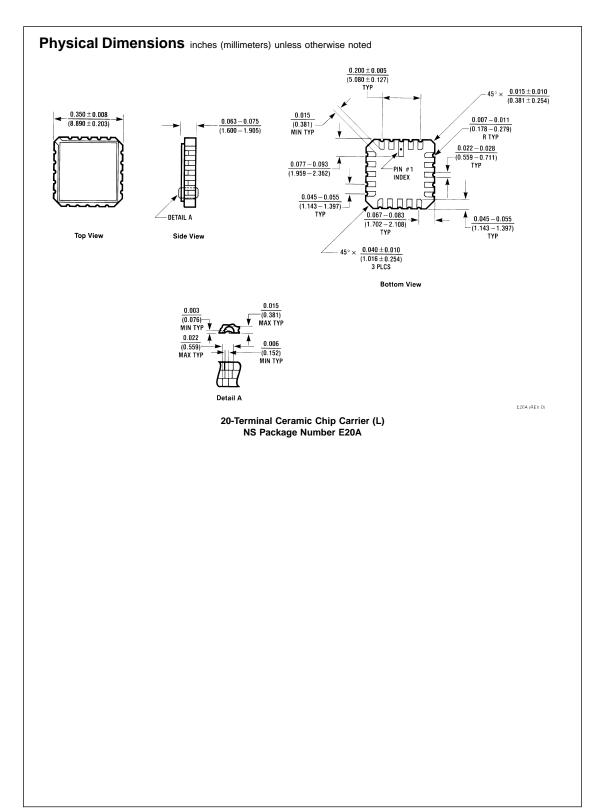
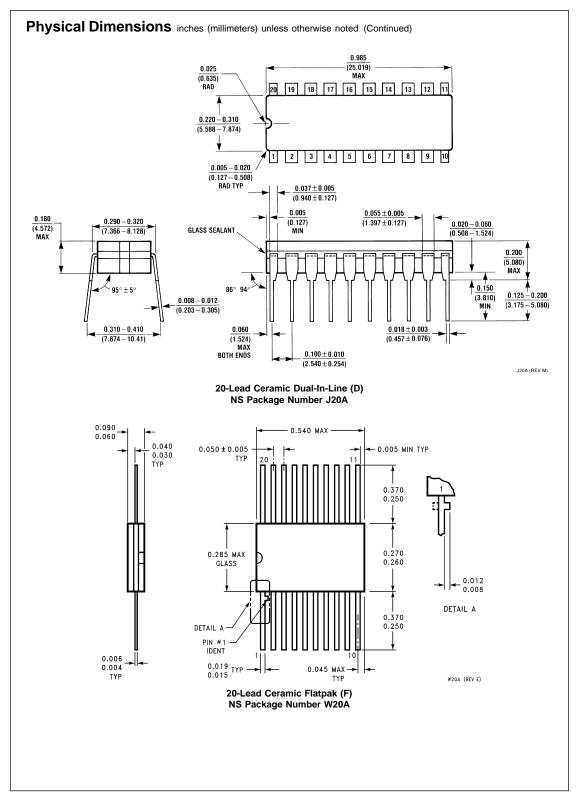


FIGURE 7. Setup Time, Hold Time and Recovery Time Waveforms







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